COMPLIANT

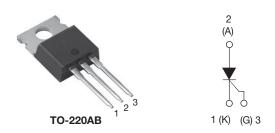
HALOGEN

FREE



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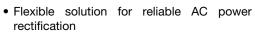
High Voltage, Phase Control Thyristor, 12 A

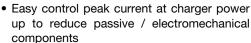


PRIMARY CHARACTERISTICS							
I _{T(AV)} 8 A							
V _{DRM} /V _{RRM}	800 V						
V _{TM}	1.2 V						
I _{GT}	15 mA						
TJ	-40 to +125 °C						
Package	TO-220AB						
Circuit configuration	Single SCR						

FEATURES

- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test





• Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-12TTS08HM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS								
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	13.5	17	А					

MAJOR RATINGS AND CHARACTERISTICS								
PARAMETER	TEST CONDITIONS	VALUES	UNITS					
I _{T(AV)}	Sinusoidal waveform	8	Δ.					
I _{T(RMS)}		12.5	A					
V_{RRM}/V_{DRM}		800	V					
I _{TSM}		110	А					
V _T	8 A, T _J = 25 °C	1.2	V					
dV/dt		150	V/µs					
dl/dt		100	A/µs					
T _J	Range	-40 to +125	°C					

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} / I _{DRM} AT 125 °C mA						
VS-12TTS08HM3	800	800	5.0						



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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average on-state current	I _{T(AV)}	T = 100 °C 190° conduction half sine ways	8	^				
Maximum RMS on-state current	I _{T(RMS)}	T _C = 108 °C, 180° conduction, half sine wave	12.5					
Maximum peak one-cycle	1	10 ms sine pulse, rated V _{RRM} applied, T _J = 125 °C	95	Α				
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied, T _J = 125 °C	110					
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied, T_J = 125 °C	45	A ² s				
Maximum i-t for fusing	I-t	10 ms sine pulse, no voltage reapplied, T _J = 125 °C	64					
Maximum I ² √t for fusing	I ² √t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C	640	A²√s				
Maximum on-state voltage drop	V_{TM}	8 A, T _J = 25 °C	1.2	V				
On-state slope resistance	r _t	T _{.1} = 125 °C	16.2	mΩ				
Threshold voltage	V _{T(TO)}	1J = 123 0	0.87	V				
Maximum reverse and direct leakage current	1/1	$T_J = 25 ^{\circ}\text{C}$	0.05					
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	$V_R = \text{rated } V_{RRM} / V_{DRM}$	5.0	1				
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C	30	mA				
Typical latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C	50					
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear to } 80 \text{ %, } V_{DRM} = R_g - k = \text{open}$	150	V/µs				
Maximum rate of rise of turned-on current	dl/dt		100	A/µs				

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P _{GM}		8.0	W			
Maximum average gate power	P _{G(AV)}		2.0	VV			
Maximum peak positive gate current	+I _{GM}		1.5	Α			
Maximum peak negative gate voltage	-V _{GM}		10	V			
		Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA			
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	15				
		Anode supply = 6 V, resistive load, T _J = 125 °C	10				
		Anode supply = 6 V, resistive load, T _J = -65 °C	1.2				
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V			
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V			
Maximum DC gate voltage not to trigger V _{GI}		T = 105 °C V = roted value	0.2				
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = rated value	0.1	mA			

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8					
Typical reverse recovery time	t _{rr}	T _{.I} = 125 °C	3	μs				
Typical turn-off time	t _q	1J = 125 O	100					



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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5				
Maximum thermal resistance, junction to ambient	R _{thJA}		62	°C/W			
Typical thermal resistance, case to heatsink		Mounting surface, smooth, and greased	0.5				
Approximate weight			2	g			
Approximate weight			0.07	oz.			
Mounting torque	minimum		6 (5)	kgf · cm			
Mounting torque	maximum		12 (10)	($lbf \cdot in$)			
Marking device		Case style TO-220AB	12TT	S08H			

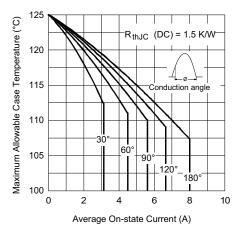


Fig. 1 - Current Rating Characteristics

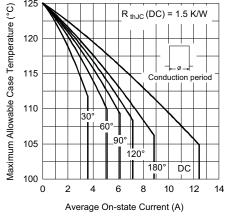


Fig. 2 - Current Rating Characteristics

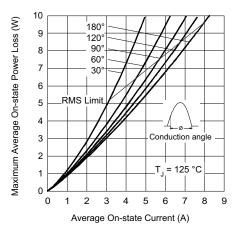


Fig. 3 - On-State Power Loss Characteristics

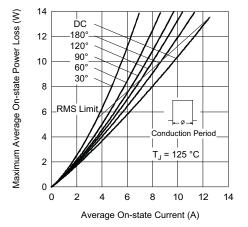


Fig. 4 - On-State Power Loss Characteristics

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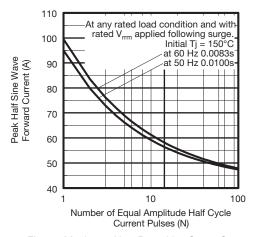


Fig. 5 - Maximum Non-Repetitive Surge Current

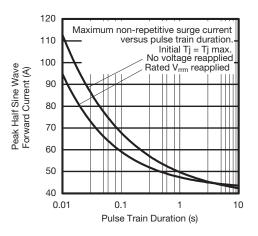


Fig. 6 - Maximum Non-Repetitive Surge Current

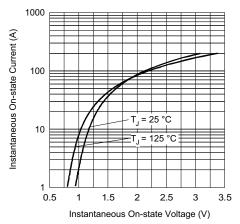


Fig. 7 - On-State Voltage Drop Characteristics

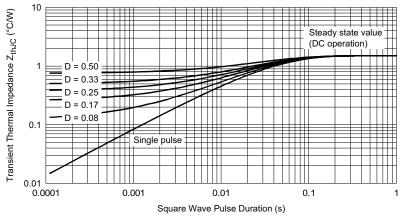


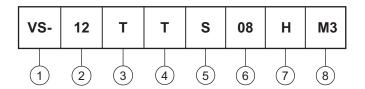
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (12.5 A)

3 - Circuit configuration:

T = single thyristor

4 - Package:

T = TO-220

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (08 = 800 V)

7 - H = AEC-Q101 qualified

8 - Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-12TTS08HM3	50	1000	Antistatic plastic tube					

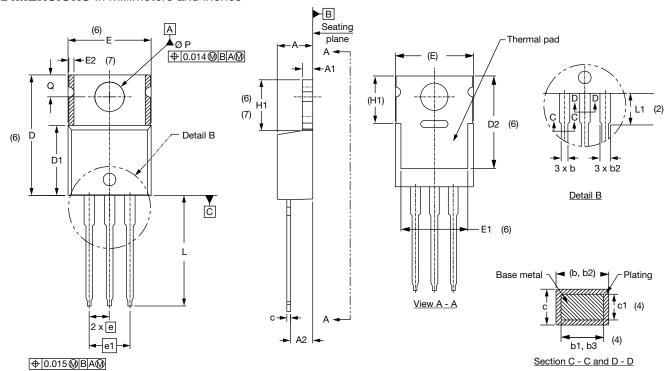
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Part marking information	www.vishay.com/doc?95028				

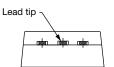


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TO-220AB

DIMENSIONS in millimeters and inches





Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	CHES		NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	12.88	0.460	0.507	6
A1	1.14	1.40	0.045	0.055			Е	10.11	10.51	0.398	0.414	3, 6
A2	2.56	2.92	0.101	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			E2	ı	0.76	-	0.030	7
b1	0.38	0.97	0.015	0.038	4		е	2.41	2.67	0.095	0.105	
b2	1.20	1.73	0.047	0.068			e1	4.88	5.28	0.192	0.208	
b3	1.14	1.73	0.045	0.068	4		H1	5.84	6.86	0.230	0.270	6, 7
С	0.36	0.61	0.014	0.024			L	13.52	14.02	0.532	0.552	
c1	0.36	0.56	0.014	0.022	4		L1	3.32	3.82	0.131	0.150	2
D	14.85	15.25	0.585	0.600	3		ØР	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Revision: 23-Feb-2024 1 Document Number: 95222



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